TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (PCT PROCESS)

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SWITCHING REGULATOR APPLICATIONS
HIGH VOLTAGE SWITCHING APPLICATIONS
DC-DC CONVERTER APPLICATIONS

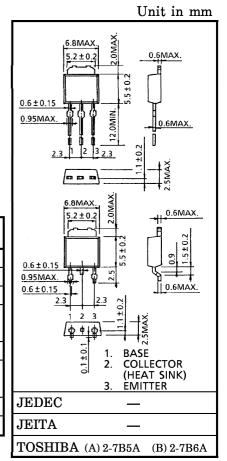
• Excellent Switching Times : $t_f = 0.5 \,\mu s$ (Max.) ($I_C = 1.2 \,A$)

• High Collectors Breakdown Voltage : $V_{CEO} = 800 \text{ V}$

• High DC Current Gain : $h_{FE} = 15$ (Min.) ($I_C = 0.15 A$)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERIS	SYMBOL	RATING	UNIT		
Collector-Base Voltage		v_{CBO}	900	V	
Collector-Emitter Voltage		v_{CEO}	800	V	
Emitter-Base Voltage	$ m V_{EBO}$	7	V		
Collector Current	DC	$I_{\mathbf{C}}$	3	A	
	Pulse	I_{CP}	5		
Base Current	$I_{ m B}$	1	A		
Collector Power	$Ta = 25^{\circ}C$	$P_{\mathbf{C}}$	1.5	w	
Dissipation	$Tc = 25^{\circ}C$	10	25		
Junction Temperature	$T_{ m j}$	150	°C		
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~150	°C	



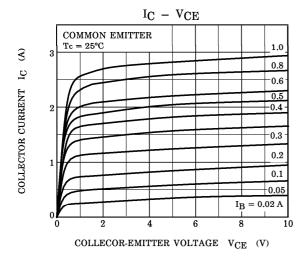
Weight: 0.36 g (Typ.)

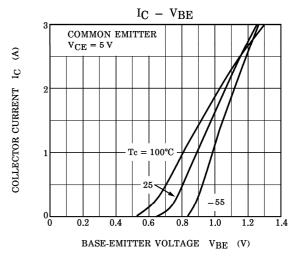
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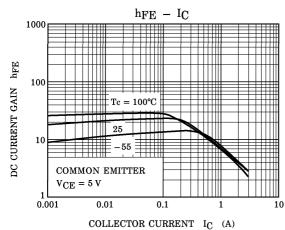
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

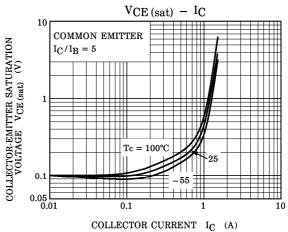
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB} = 720 \text{ V}, I_{E} = 0$	_	_	100	μ A
Emitter Cut-off Current		I_{EBO}	$V_{EB} = 7 \text{ V}, I_{C} = 0$	_	_	10	μ A
Collector-Base Breakdown Voltage		V (BR) CBO	$I_{\mathrm{C}}=1\mathrm{mA},~I_{\mathrm{B}}=0$	900	_	_	V
Collector-Emitter Breakdown Voltage		V (BR) CEO	$I_{\rm C} = 10 {\rm mA}, \; I_{\rm B} = 0$	800	_	_	V
DC Current Gain		h _{FE} (1) h _{FE} (2)	$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ mA}$ $V_{CE} = 5 \text{ V}, I_{C} = 0.15 \text{ A}$	10 15	_	_	
Collector-Emitter Saturation Voltage		V _{CE} (sat)	$I_{C} = 1.2 A, I_{B} = 0.24 A$	_	_	1.0	V
Base-Emitter Saturation Voltage		V _{BE} (sat)	$I_{\rm C} = 1.2{\rm A},~I_{\rm B} = 0.24{\rm A}$	_	_	1.3	V
Switching Time Storage T	Rise Time	t_r	$I_{B1} \stackrel{20 \mu\text{s}}{\longleftarrow} V_{CC} = 360 \text{V}_{CC}$ $I_{B1} \stackrel{I_{C}}{\longleftarrow} \stackrel{\circ}{\longleftarrow} 0$ $I_{B2} \stackrel{\bullet}{\longleftarrow} 0$	_	_	0.7	
	Storage Time	t_{stg}		_	_	4.0	μ s
	Fall Time	tf	$I_{B1} = 0.24 \text{ A}, I_{B2} = -0.48 \text{ A}$ $DUTY \text{ CYCLE} \leq 1\%$	_	_	0.5	

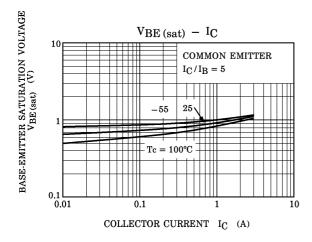
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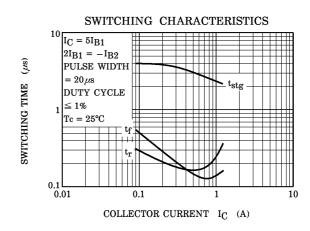




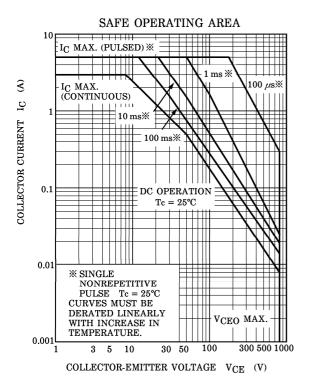








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